

10/ 765-100

PTO/SB/17 (10-07)

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U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

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Effective on 12/08/2004.
Fees pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).

FEE TRANSMITTAL **For FY 2008**

☐ Applicant claims small entity status. See 37 CFR 1.27

TOTAL AMOUNT OF PAYMENT

(\$) 100.00

Complete if Known

Application Number	Patent#: 7,023,025B2
Filing Date	Issued: April 4, 2006
First Named Inventor	Johngoon SHIN
Examiner Name	M. H. C. Tran
Art Unit	2818
Attorney Docket No.	1630-0135P

METHOD OF PAYMENT (check all that apply)

☐ Check ☐ Credit Card ☐ Money Order ☐ None ☐ Other (please identify): _____
☒ Deposit Account Deposit Account Number: 02-2448 Deposit Account Name: Birch, Stewart, Kolasch & Birch, LLP

For the above-identified deposit account, the Director is hereby authorized to: (check all that apply)

☒ Charge fee(s) indicated below ☐ Charge fee(s) indicated below, except for the filing fee
☐ Charge any additional fee(s) or underpayments of fee(s) under 37 CFR 1.16 and 1.17 ☒ Credit any overpayments

FEE CALCULATION
1. BASIC FILING, SEARCH, AND EXAMINATION FEES

Application Type	FILING FEES		SEARCH FEES		EXAMINATION FEES		Fees Paid (\$)
	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	
Utility	310	155	510	255	210	105	
Design	210	105	100	50	130	65	
Plant	210	105	310	155	160	80	
Reissue	310	155	510	255	620	310	
Provisional	210	105	0	0	0	0	

2. EXCESS CLAIM FEES
Fee Description

	Fee (\$)	Small Entity Fee (\$)
Each claim over 20 (including Reissues)	50	25
Each independent claim over 3 (including Reissues)	210	105
Multiple dependent claims	370	185

Total Claims Extra Claims Fee (\$) Fee Paid (\$)
 - = x =

HP = highest number of total claims paid for, if greater than 20.

Indep. Claims Extra Claims Fee (\$) Fee Paid (\$)
 - = x =

HP = highest number of independent claims paid for, if greater than 3.

3. APPLICATION SIZE FEE

If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$260 (\$130 for small entity) for each additional 50 sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).

Total Sheets Extra Sheets Number of each additional 50 or fraction thereof Fee (\$) Fee Paid (\$)
 - 100 = /50 = (round up to a whole number) x =

4. OTHER FEE(S)

Non-English Specification, \$130 fee (no small entity discount)

Other (e.g., late filing surcharge): 1811 Certificate of correction

Fees Paid (\$)

100.00

SUBMITTED BY

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Name (Print/Type)	James T. Eller, Jr.	Date	October 19, 2007		

Certificate
 OCT 23 2007
 of Correction



Docket No.: 1630-0135P
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
Johngeon SHIN

Patent No.: 7,023,025B2

Issued: April 4, 2006

For: CRYSTAL GROWTH METHOD OF NITRIDE
SEMICONDUCTOR

**REQUEST FOR CERTIFICATE OF CORRECTION
PURSUANT TO 37 CFR 1.322**

Attention: Certificate of Correction Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Upon reviewing the above-identified patent, Patentee noted a typographical error which should be corrected as follows.

Claim 1, as originally filed January 28, 2004, recited "a first nitride buffer layer". However, the amendment filed September 26, 2005 inadvertently omitted the word "buffer" from the limitation "a first nitride buffer layer" (i.e. the limitation currently reads "a first nitride layer"). Subsequent limitations in claim 1 refer back to "said first nitride buffer layer". Therefore, it should be clear that this omission of the word "buffer" was an obvious typographical error, and that the correction does not introduce any new matter or change the scope of the claims in any way. The present Request for Certificate of Correction is being filed to correct this obvious omission.

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Patent No.: 7,023,025B2

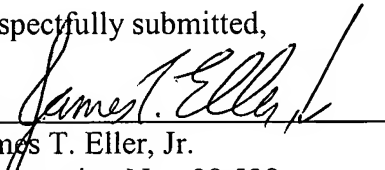
Docket No.: 1630-0135P

Transmitted herewith is a proposed Certificate of Correction effecting such amendment.
Patentee respectfully solicits the granting of the requested Certificate of Correction.

Dated: October 19, 2007

Respectfully submitted,

By


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**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**Page 1 of 1

PATENT NO. : 7,023,025B2
APPLICATION NO. : 10/765,100
ISSUE DATE : April 4, 2006
INVENTOR(S) : Johngeon SHIN

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 4, claim 1, line 3 thereof: "a first nitride layer" should read
--a first nitride buffer layer--

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